

650V SiC Schottky Diode

Amp+[™] Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 135mJ*

Amp+[™] Benefits

- Zero switching loss
- Higher efficiency
- Smaller heat sink
- · Easy to parallel

Amp+[™] Applications

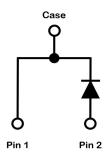
- Switch mode power supplies, UPS
- Power factor correction
- EV charging stations
- Output rectification

GP3D020A065A

VDC	650 V
Qc	52 nC
I _F	20 A
T _j ,max	175 °C







Part #	Package	Marking
GP3D020A065A	TO-220-2L	3D020A065



Maximum Ratings, at Ti=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values	Unit	
Continuous forward current	I _F **	T _C =25 °C, T _j =175 °C	54		
		T _C =125 °C, T _j =175 °C	29	A	
		T _C =150 °C, T _j =175 °C	19		
Surge non-repetitive forward current	1	T _C =25 °C, t _p =8.3 ms	135		
sine halfwave	I _{FSM}	T _C =110 °C, t _p =8.3 ms	125	— A	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	850	A	
<i>i²t</i> value	∫i²dt	T _C =25 °C, t _p =8.3 ms	76	— A ² s	
		T _C =110 °C, t _p =8.3 ms	65		
Repetitive peak reverse voltage	V _{RRM}	T _j =25 °C	650	V	
Diode <i>dv/dt</i> ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns	
Power dissipation	P _{tot} **	T _C =25 °C	197	W	
Operating junction & storage temperature	T _j , T _{storage}	Continuous	-55175	°C	
Soldering temperature	T _{solder}	Wave soldering leads	260	°C	
Mounting torque		M3 Screw	1	N-m	

Notes:

* EAS of 135 mJ is based on starting Tj = 25°C, L = 1.0 mH, IAS = 16.43 A, V = 50 V.

**Typical Rth_{JC} used

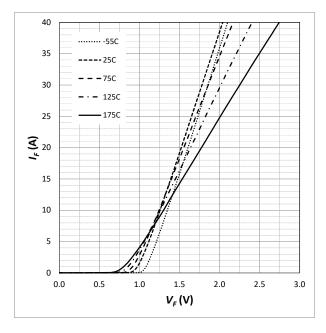
Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Onit
DC blocking voltage	V _{DC}	T _j =25 °C	650	-	-	V
		I _F =20A, T _j =25 °C	-	1.52	1.70	
Diode forward voltage		I _F =20A, T _j =125 °C	-	1.64	-	V
		I _F =20A, T _j =175 °C	-	1.78	2.20	
Reverse current	I _R	V _R =650V, T _j =25 °C	-	3	50	μΑ
		V _R =650V, T _j =125 °C	-	19	-	
		V _R =650V, T _j =175 °C	-	65	500	
Total capacitive charge	Q _C	V _R =400V, T _j =25 °C	-	52	-	nC
		V _R =1V, f=1 MHz	-	835	-	
Total capacitance	С	V _R =200V, f=1 MHz	-	99	-	pF
		V _R =400V, f=1 MHz	-	83	-	

Electrical Characteristics, at T_j=25 °C, unless otherwise specified

Thermal Characteristics

Characteristics	Symbol Conditions		Values			Unit
	Symbol	Conditions	min.	typ.	max.	onne
Thermal resistance, junction-case	R _{thJC}	-	-	0.76	1.00	°C/W

Typical Performance





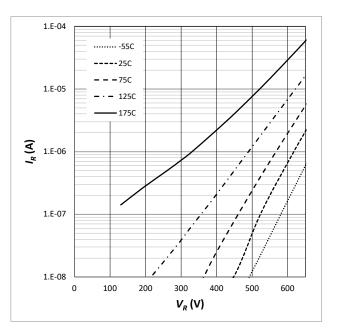
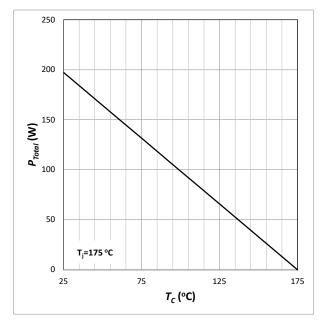


Fig. 2 Reverse Characteristics (parameterized on T_i)



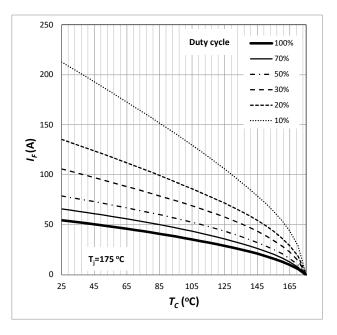
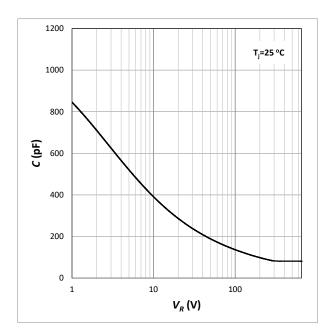


Fig. 3 Power Derating

Fig. 4 Current Derating



80 T_j=25 °C 70 60 50 0⁴⁰ (Dr) 30 20 10 0 0 100 200 300 400 500 600 $V_R(V)$

Fig. 5 Capacitance

Fig. 6 Capacitive Charge

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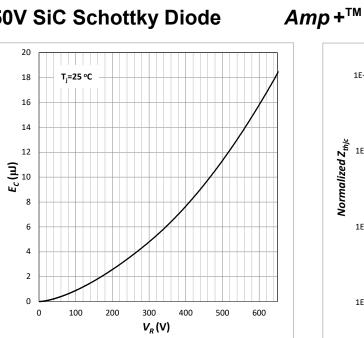
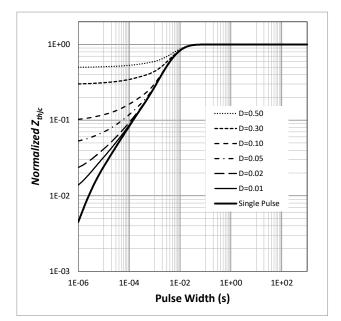


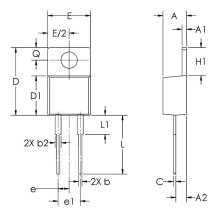
Fig. 7 Typical Capacitance Stored Energy

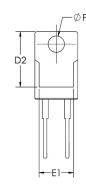


GP3D020A065A



Package Dimensions TO-220-2L





Sym Millimeters		neters	Inc	hes
Sym	Min	Max	Min	Max
А	3.56	4.83	0.140	0.190
A1	0.51	1.40	0.020	0.055
A2	2.03	2.92	0.080	0.115
b	0.38	1.02	0.015	0.040
b2	1.02	1.78	0.040	0.070
С	0.36	0.76	0.014	0.030
D	14.22	16.51	0.560	0.650
D1	8.38	9.40	0.330	0.370
D2	12.19	13.13	0.480	0.517
E	9.65	10.67	0.380	0.420
E1	6.86	8.89	0.270	0.350
е	2.54	2.54 BSC		BSC
e1	5.08 BSC		.200 BSC	
H1	5.84	6.86	0.230	0.270
L	12.57	14.73	0.495	0.580
L1	3.60	6.35	0.142	0.250
ØP	3.53	4.09	0.139	0.161
Q	2.54	3.43	0.100	0.135

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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